



### 100V N-Channel Enhancement Mode MOSFET

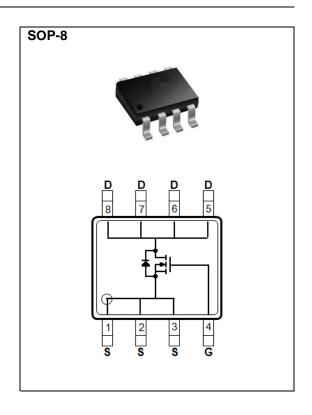
Voltage 100 V Current 5 A

#### **Features**

- RDS(ON), VGS@10V, ID@5A<50mΩ</li>
- RDS(ON), VGS@4.5V, ID@3A<55mΩ</li>
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

- Case: SOP-8 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams
- Marking: L9454A



## **Maximum Ratings and Thermal Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETE	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		$V_{DS}$	100	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>A</sub> =25°C		5	А	
	T <sub>A</sub> =70°C	I <sub>D</sub>	4		
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	20	А	
Power Dissipation	T <sub>A</sub> =25°C	)	2.5		
	T <sub>A</sub> =70°C	P <sub>D</sub>	1.6	W	
Single Pulse Avalanche Energy (Note 5)		E <sub>AS</sub>	5	mJ	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C	
Typical Thermal resistance - Junction to Ambient, $t \le 10s^{\text{(Note 6)}}$		$R_{ hetaJA}$	50	°C/W	





## **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =250uA	100	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	1.0	1.5	2.5	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V,I <sub>D</sub> =5A	-	37	50	mΩ	
		$V_{GS}$ =4.5 $V$ , $I_D$ =3 $A$	-	38	55		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =80V, $V_{GS}$ =0V	-	-	1.0	uA	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 7)							
Total Gate Charge	$Q_g$	V <sub>DS</sub> =80V, I <sub>D</sub> =5A, V <sub>GS</sub> =10V <sup>(Note 1,2)</sup>	-	55	-	nC	
Gate-Source Charge	$Q_gs$		-	7.9	-		
Gate-Drain Charge	$Q_gd$		-	10	-		
Input Capacitance	Ciss	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	3601	-	pF	
Output Capacitance	Coss		-	133	-		
Reverse Transfer Capacitance	Crss		-	65	-		
Turn-On Delay Time	td <sub>(on)</sub>		-	14	-	ns	
Turn-On Rise Time	tr	$V_{DD}$ =50V, $I_{D}$ =5A, $V_{GS}$ =10V, $R_{G}$ =3 $\Omega$ (Note 1,2)	-	45	-		
Turn-Off Delay Time	td <sub>(off)</sub>		-	57	-		
Turn-Off Fall Time	tf		-	16	-		
Drain-Source Diode							
Maximum Continuous Drain-Source			-	-	5.0	А	
Diode Forward Current	I <sub>S</sub>						
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.7	1.2	V	

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited.
- 5. The test condition is L=0.1mH,  $I_{AS}$ =10A,  $V_{DD}$ =50V,  $V_{GS}$ =10V
- 6. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 7. Guaranteed by design, not subject to production testing.





### **TYPICAL CHARACTERISTIC CURVES**

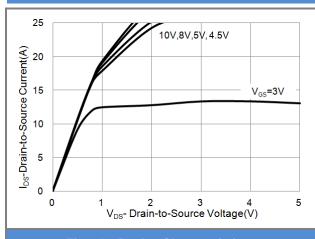
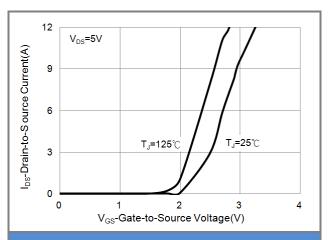


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

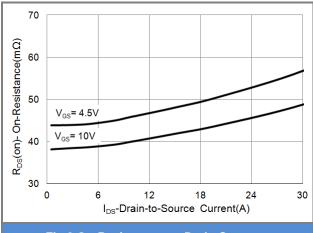


Fig.3 On-Resistance vs. Drain Current

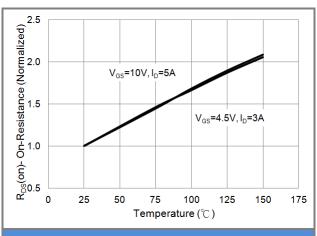


Fig.4 On-Resistance vs. Junction temperature

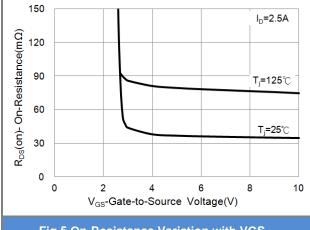


Fig.5 On-Resistance Variation with VGS.

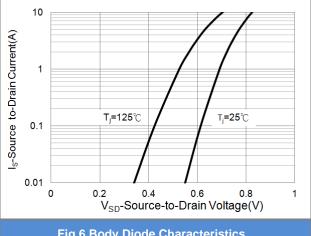


Fig.6 Body Diode Characteristics





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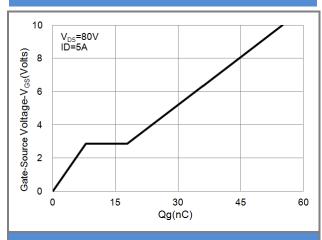


Fig.7 Gate-Charge Characteristics

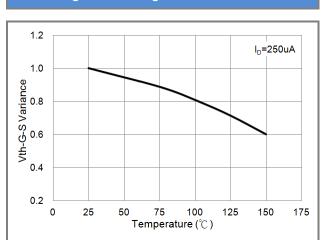
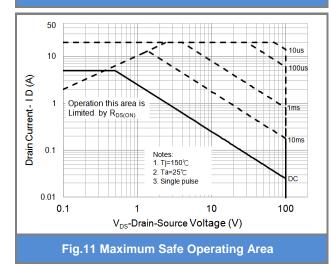


Fig.9 Threshold Voltage Variation with Temperature.



1.2 I<sub>D</sub>=250uA (Notation of the content of the cont

Fig.8 Breakdown Voltage Variation vs. Temperature

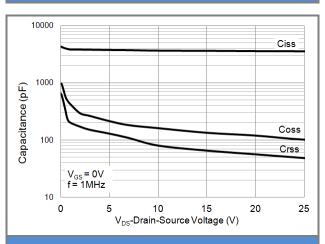


Fig.10 Capacitance vs. Drain-Source Voltage.





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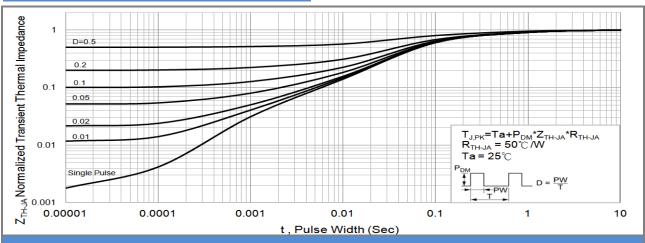


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

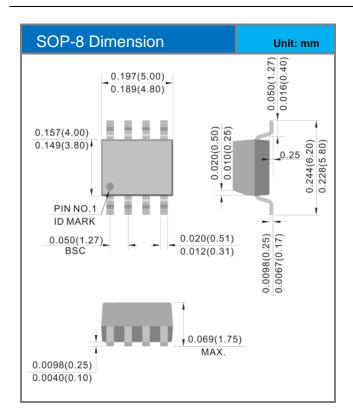


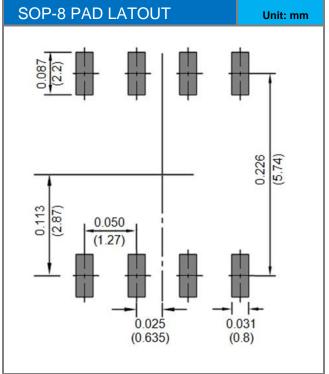


### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version	
PJL9454A_R2_00001	SOP-8	2.5K pcs / 13" reel	L9454A	Halogen free	

### Packaging Information & Mounting Pad Layout









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